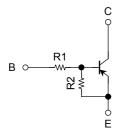
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

RN2107FT,RN2108FT,RN2109FT

Switching, Inverter Circuit, Interface Circuit and **Driver Circuit Applications.**

- High-density mount is possible because of devices housed in very thin TESM packages.
- Incorporating a bias resistor into a transistor reduces parts count. Reducing the parts count enable the manufacture of ever more compact equipment and save assembly cost.
- Wide range of resistor values are available to use in various circuit
- Complementary to RN1107FT, RN1108FT, RN1109FT

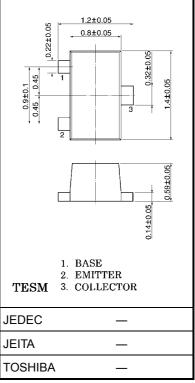
Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2107FT	10	47
RN2108FT	22	47
RN2109FT	47	22

1.2±0.05 0.8±0.05

Unit: mm



Weight: g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	nbol Rating		
Collector-base voltage	RN2107FT~2109FT	V _{CBO}	-50	٧	
Collector-emitter voltage	KIN21071 1 - 21091 1	V _{CEO}	-50	V	
	RN2107FT		-6		
Emitter-base voltage	RN2108FT V _{EBO}		-7	V	
	RN2109FT		-15		
Collector current		I _C	-100	mA	
Collector power dissipation	RN2107FT~2109FT	P _C	100	mW	
Junction temperature	KN2107F1~2109F1	Tj	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	



Electrical Characteristics (Ta = 25°C)

Charac	teristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2107FT~2109FT	I _{CBO}	$V_{CB} = -50 \text{ V}, I_E = 0$	_	_	-100	- nA
		I _{CEO}	$V_{CE} = -50 \text{ V}, I_B = 0$	_	_	-500	
	RN2107FT		$V_{EB} = -6 \text{ V}, I_C = 0$	-0.081	_	-0.15	
Emitter cut-off current	RN2108FT	I _{EBO}	$V_{EB} = -7 \text{ V, } I_{C} = 0$	-0.078	_	-0.145	mA
	RN2109FT		$V_{EB} = -15 \text{ V}, I_C = 0$	-0.167	_	-0.311	
	RN2107FT		V _{CE} = -5 V, I _C = -10 mA	80	_	_	
DC current gain	RN2108FT	h _{FE}		80	_	_	
	RN2109FT			70	_	_	
Collector-emitter saturation voltage	RN2107FT~2109FT	V _{CE} (sat)	$I_C = -5 \text{ mA},$ $I_B = -0.25 \text{ mA}$	_	-0.1	-0.3	V
Input voltage (ON)	RN2107FT	V _{I (ON)}	V _{CE} = -0.2 V, I _C = -5 mA	-0.7	_	-1.8	V
	RN2108FT			-1.0	_	-2.6	
	RN2109FT			-2.2	_	-5.8	
	RN2107FT	V _{I (OFF)}	V _{CE} = -5 V, I _C = -0.1 mA	-0.5	_	-1.0	V
Input voltage (OFF)	RN2108FT			-0.6	_	-1.16	
	RN2109FT			-1.5	_	-2.6	
Transition frequency	RN2107FT~2109FT	f _T	$V_{CE} = -10 \text{ V},$ $I_{C} = -5 \text{ mA}$	_	200		٧
Collector output capacitance	RN2107FT~2109FT	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0,$ f = 1 MHz	_	3	6	pF
Input resistor	RN2107FT	R1	_	7	10	13	kΩ
	RN2108FT			15.4	22	28.6	
	RN2109FT			32.9	47	61.1	
Resistor ratio	RN2107FT	R1/R2	_	0.919	0.213	0.232	
	RN2108FT			0.421	0.468	0.515	
	RN2109FT			1.92	2.14	2.35	

2

Type Name	Marking
RN1107FT	Type name
RN1108FT	Type name
RN1109FT	Type name

3

RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other
 rights of the third parties which may result from its use. No license is granted by implication or otherwise under
 any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.